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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	RL78
Core Size	16-Bit
Speed	24MHz
Connectivity	CSI, I <sup>2</sup> C, UART/USART
Peripherals	LVD, POR, PWM, WDT
Number of I/O	18
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1.5K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 11x8/10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	24-WQFN Exposed Pad
Supplier Device Package	24-HWQFN (4x4)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f1037aana-u5">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f1037aana-u5</a>

### 1.3 Differences between the R5F102 Products and the R5F103 Products

The following are differences between the R5F102 products and the R5F103 products.

- Whether the data flash memory is mounted or not
- High-speed on-chip oscillator oscillation frequency accuracy
- Number of channels in serial interface
- Whether the DMA function is mounted or not
- Whether a part of the safety functions are mounted or not

#### 1.3.1 Data Flash

The data flash memory of 2 KB is mounted on the R5F102 products, but not on the R5F103 products.

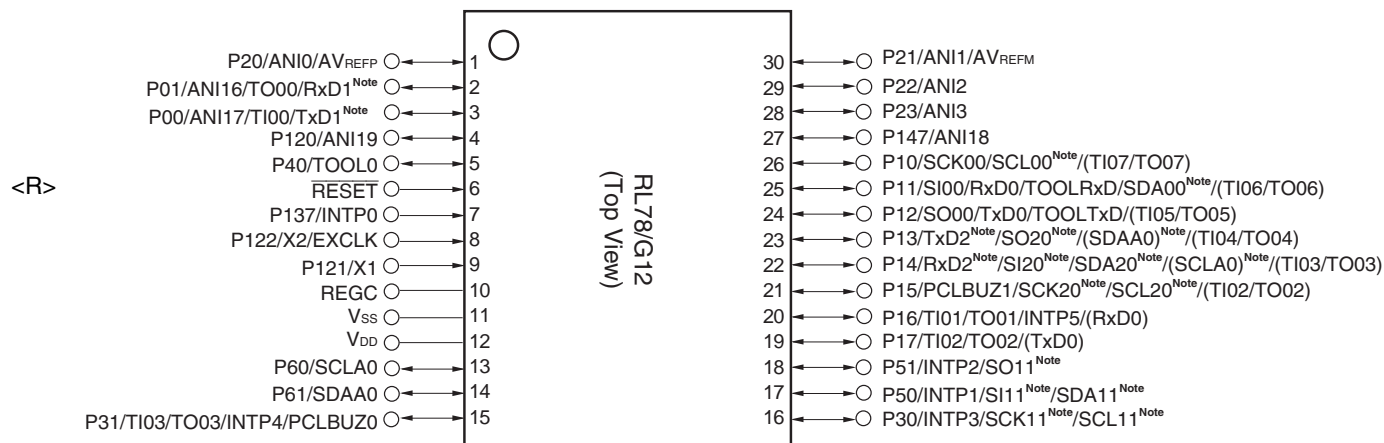
Product	Data Flash
<b>R5F102 products</b> R5F1026A, R5F1027A, R5F102AA, R5F10269, R5F10279, R5F102A9, R5F10268, R5F10278, R5F102A8, R5F10267, R5F10277, R5F102A7, R5F10266 <sup>Note</sup>	2KB
<b>R5F103 products</b> R5F1036A, R5F1037A, R5F103AA, R5F10369, R5F10379, R5F103A9, R5F10368, R5F10378 R5F103A8, R5F10367, R5F10377, R5F103A7, R5F10366	Not mounted

**Note** The RAM in the R5F10266 has capacity as small as 256 bytes. Depending on the customer's program specification, the stack area to execute the data flash library may not be kept and data may not be written to or erased from the data flash memory.

**Caution** When the flash memory is rewritten via a user program, the code flash area and RAM area are used because each library is used. When using the library, refer to RL78 Family Flash Self Programming Library Type01 User's Manual and RL78 Family Data Flash Library Type04 User's Manual.

## 1.4.3 30-pin products

- 30-pin plastic LSSOP (7.62 mm (300), 0.65 mm pitch)



**Note** Provided only in the R5F102 products.

**Caution** Connect the REGC pin to V<sub>SS</sub> via capacitor (0.47 to 1  $\mu$ F).

**Remarks 1.** For pin identification, see **1.5 Pin Identification**.

**2.** Functions in parentheses in the above figure can be assigned via settings in the peripheral I/O redirection register (PIOR). See **Figure 4-8 Format of Peripheral I/O Redirection Register (PIOR)**.

## <R> 2. ELECTRICAL SPECIFICATIONS ( $T_A = -40$ to $+85^\circ\text{C}$ )

<R> This chapter describes the following electrical specifications.

Target products A: Consumer applications  $T_A = -40$  to  $+85^\circ\text{C}$

<R> R5F102xxAxx, R5F103xxAxx

D: Industrial applications  $T_A = -40$  to  $+85^\circ\text{C}$

<R> R5F102xxDxx, R5F103xxDxx

G: Industrial applications when  $T_A = -40$  to  $+105^\circ\text{C}$  products is used in the range of  $T_A = -40$  to  $+85^\circ\text{C}$

<R> R5F102xxGxx

**Cautions** 1. The RL78 microcontrollers have an on-chip debug function, which is provided for development and evaluation. Do not use the on-chip debug function in products designated for mass production, because the guaranteed number of rewritable times of the flash memory may be exceeded when this function is used, and product reliability therefore cannot be guaranteed. Renesas Electronics is not liable for problems occurring when the on-chip debug function is used.

2. The pins mounted depend on the product. Refer to 2.1 Port Functions to 2.2.1 Functions for each product.

## 2.3.2 Supply current characteristics

## (1) 20-, 24-pin products

 $(T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V})$ 

(1/2)

Parameter	Symbol	Conditions					MIN.	TYP.	MAX.	Unit
Supply current <sup>Note 1</sup>	I <sub>DD1</sub>	Operating mode	HS(High-speed main) mode <sup>Note 4</sup>	f <sub>IH</sub> = 24 MHz <sup>Note 3</sup>	Basic operation	V <sub>DD</sub> = 5.0 V		1.5		mA
						V <sub>DD</sub> = 3.0 V		1.5		
					Normal operation	V <sub>DD</sub> = 5.0 V		3.3	5.0	mA
						V <sub>DD</sub> = 3.0 V		3.3	5.0	
						f <sub>IH</sub> = 16 MHz <sup>Note 3</sup>	V <sub>DD</sub> = 5.0 V		2.5	3.7
				V <sub>DD</sub> = 3.0 V			2.5	3.7		
				LS(Low-speed main) mode <sup>Note 4</sup>	f <sub>IH</sub> = 8 MHz <sup>Note 3</sup>	V <sub>DD</sub> = 3.0 V		1.2	1.8	mA
						V <sub>DD</sub> = 2.0 V		1.2	1.8	
				HS(High-speed main) mode <sup>Note 4</sup>	f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V	Square wave input		2.8	4.4	mA
						Resonator connection		3.0	4.6	
			f <sub>MX</sub> = 20 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V			Square wave input		2.8	4.4	mA
						Resonator connection		3.0	4.6	
			f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 5.0 V		Square wave input		1.8	2.6	mA	
					Resonator connection		1.8	2.6		
			f <sub>MX</sub> = 10 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V		Square wave input		1.8	2.6	mA	
					Resonator connection		1.8	2.6		
			LS(Low-speed main) mode <sup>Note 4</sup>	f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 3.0 V	Square wave input		1.1	1.7	mA	
					Resonator connection		1.1	1.7		
				f <sub>MX</sub> = 8 MHz <sup>Note 2</sup> , V <sub>DD</sub> = 2.0 V	Square wave input		1.1	1.7	mA	
					Resonator connection		1.1	1.7		

**Notes** 1. Total current flowing into  $V_{DD}$ , including the input leakage current flowing when the level of the input pin is fixed to  $V_{DD}$  or  $V_{SS}$ . The values below the MAX. column include the peripheral operation current. However, not including the current flowing into the A/D converter, LVD circuit, I/O port, and on-chip pull-up/pull-down resistors and the current flowing during data flash rewrite.

2. When high-speed on-chip oscillator clock is stopped.

3. When high-speed system clock is stopped

4. Relationship between operation voltage width, operation frequency of CPU and operation mode is as follows.

HS(High speed main) mode:  $V_{DD} = 2.7\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $24\text{ MHz}$

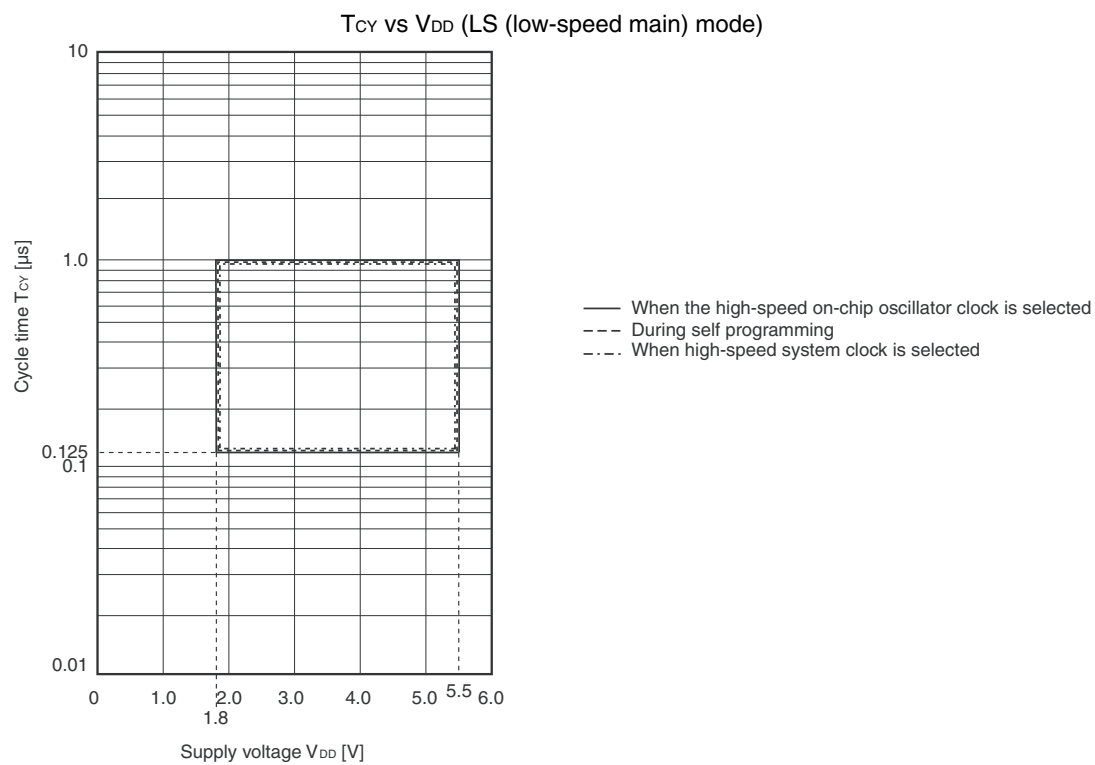
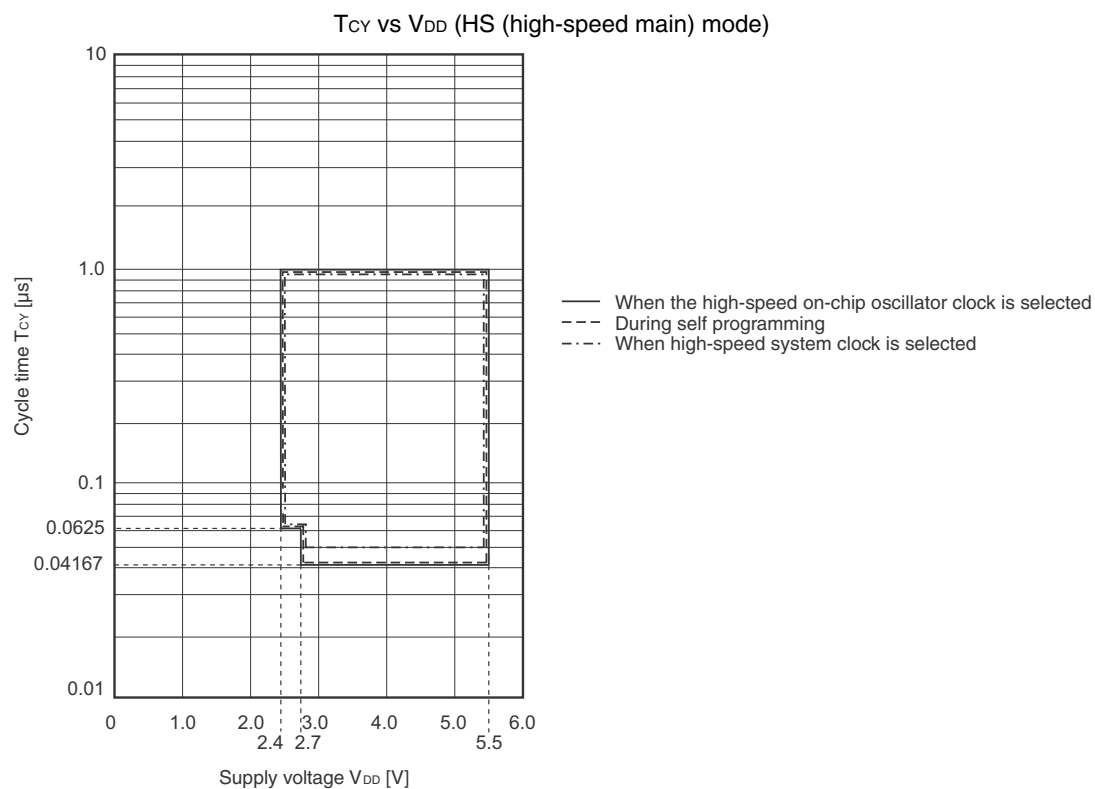
$V_{DD} = 2.4\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $16\text{ MHz}$

LS(Low speed main) mode:  $V_{DD} = 1.8\text{ V}$  to  $5.5\text{ V}$  @  $1\text{ MHz}$  to  $8\text{ MHz}$

**Remarks** 1.  $f_{MX}$ : High-speed system clock frequency (X1 clock oscillation frequency or external main system clock frequency)

2.  $f_{IH}$ : high-speed on-chip oscillator clock frequency

3. Temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$ .

**Minimum Instruction Execution Time during Main System Clock Operation**

**(8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (master mode, SCKp... internal clock output) (3/3)****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

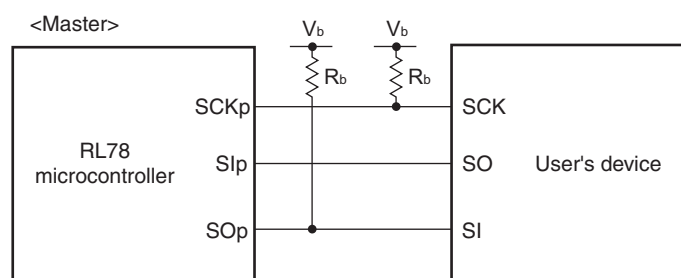
Parameter	Symbol	Conditions	HS (high-speed main) Mode		LS (low-speed main) Mode		Unit
			MIN.	MAX.	MIN.	MAX.	
Slp setup time (to SCKp↓) <sup>Note 1</sup>	$t_{SIK1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	44		110		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	44		110		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	110		110		ns
Slp hold time (from SCKp↓) <sup>Note 1</sup>	$t_{KSI1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$	19		19		ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$	19		19		ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$	19		19		ns
Delay time from SCKp↑ to SOp output <sup>Note 1</sup>	$t_{KSO1}$	$4.0\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ , $2.7\text{ V} \leq V_b \leq 4.0\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 1.4\text{ k}\Omega$		25		25	ns
		$2.7\text{ V} \leq V_{DD} < 4.0\text{ V}$ , $2.3\text{ V} \leq V_b \leq 2.7\text{ V}$ , $C_b = 30\text{ pF}$ , $R_b = 2.7\text{ k}\Omega$		25		25	ns
		$1.8\text{ V} \leq V_{DD} < 3.3\text{ V}$ , $1.6\text{ V} \leq V_b \leq 2.0\text{ V}$ <sup>Note 2</sup> , $C_b = 30\text{ pF}$ , $R_b = 5.5\text{ k}\Omega$		25		25	ns

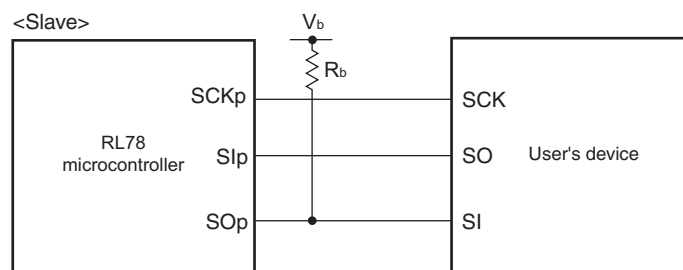
**Notes** 1. When  $DAP_{mn} = 0$  and  $CKP_{mn} = 1$ , or  $DAP_{mn} = 1$  and  $CKP_{mn} = 0$ .2. Use it with  $V_{DD} \geq V_b$ .**Cautions** 1. Select the TTL input buffer for the Slp pin and the N-ch open drain output ( $V_{DD}$  tolerance) mode for the SOp pin and SCKp pin by using port input mode register 1 (PIM1) and port output mode register 1 (POM1). For  $V_{IH}$  and  $V_{IL}$ , see the DC characteristics with TTL input buffer selected.

2. CSI01 and CSI11 cannot communicate at different potential.

**Remarks** 1.  $R_b$  [ $\Omega$ ]: Communication line (SCKp, SOp) pull-up resistance,  $C_b$  [F]: Communication line (SCKp, SOp) load capacitance,  $V_b$  [V]: Communication line voltage

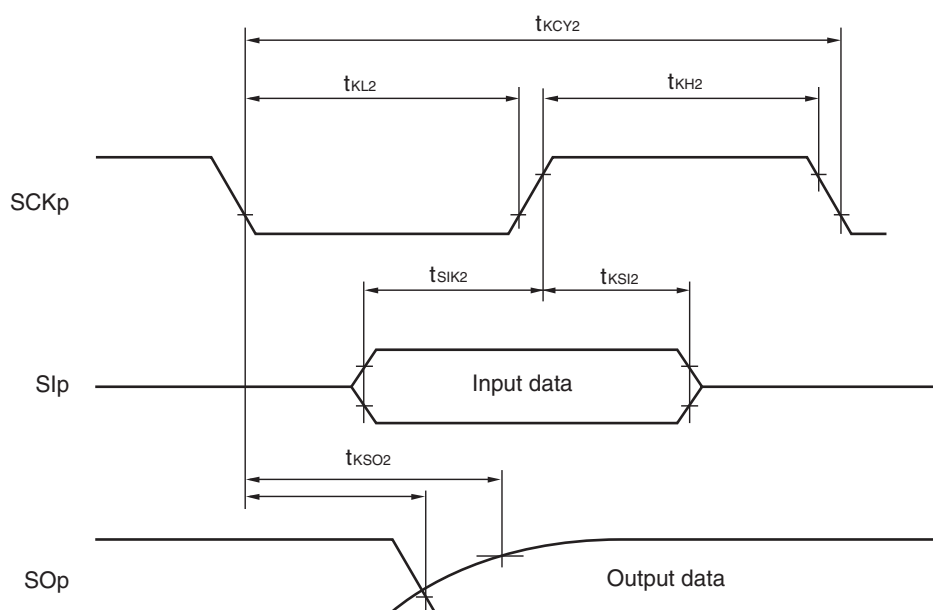
2. p: CSI number (p = 00, 20), m: Unit number (m = 0, 1), n: Channel number (n = 0)

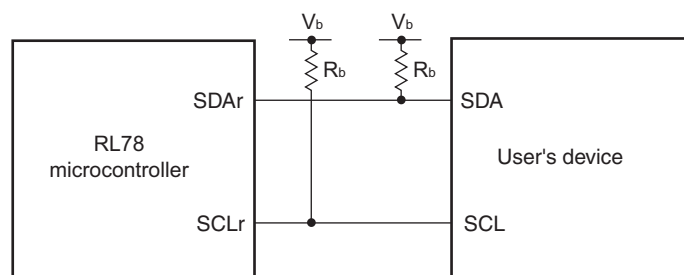
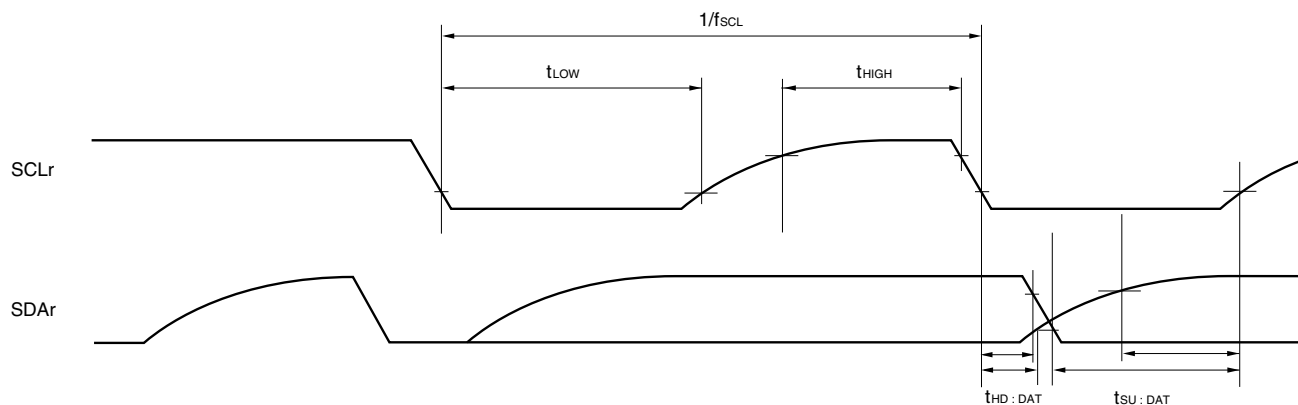
**CSI mode connection diagram (during communication at different potential)**

**CSI mode connection diagram (during communication at different potential)**

- Remarks**
1.  $R_b$  [ $\Omega$ ]: Communication line (SOp) pull-up resistance,  $C_b$  [F]: Communication line (SOp) load capacitance,  $V_b$  [V]: Communication line voltage
  2. p: CSI number ( $p = 00, 20$ ), m: Unit number ( $m = 0, 1$ ), n: Channel number ( $n = 0$ )
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register m (SPSm) and the CKSmn bit of serial mode register mn (SMRmn). m: Unit number, n: Channel number ( $mn = 00, 10$ ))

**CSI mode serial transfer timing (slave mode) (during communication at different potential)**  
**(When DAPmn = 0 and CKPmn = 0, or DAPmn = 1 and CKPmn = 1.)**



**Simplified I<sup>2</sup>C mode connection diagram (during communication at different potential)****Simplified I<sup>2</sup>C mode serial transfer timing (during communication at different potential)**

- Remarks**
1.  $R_b$  [ $\Omega$ ]: Communication line (SDAr, SCLr) pull-up resistance,  $C_b$  [F]: Communication line (SDAr, SCLr) load capacitance,  $V_b$  [V]: Communication line voltage
  2.  $r$ : IIC Number ( $r = 00, 20$ )
  3.  $f_{MCK}$ : Serial array unit operation clock frequency  
(Operation clock to be set by the serial clock select register  $m$  (SPS $m$ ) and the CKS $mn$  bit of serial mode register  $mn$  (SMR $mn$ ).  
 $m$ : Unit number ( $m = 0, 1$ ),  $n$ : Channel number ( $n = 0$ ))
  4. Simplified I<sup>2</sup>C mode is supported only by the R5F102 products.

## 2.5.2 Serial interface IICA

( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $1.8\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Symbol	Conditions	HS (high-speed main) mode LS (low-speed main) mode				Unit
			Standard Mode		Fast Mode		
			MIN.	MAX.	MIN.	MAX.	
SCLA0 clock frequency	f <sub>SCL</sub>	Fast mode: f <sub>CLK</sub> ≥ 3.5 MHz			0	400	kHz
		Normal mode: f <sub>CLK</sub> ≥ 1 MHz	0	100			kHz
Setup time of restart condition	t <sub>SU:STA</sub>		4.7		0.6		μs
Hold time <sup>Note 1</sup>	t <sub>HD:STA</sub>		4.0		0.6		μs
Hold time when SCLA0 = “L”	t <sub>LOW</sub>		4.7		1.3		μs
Hold time when SCLA0 = “H”	t <sub>HIGH</sub>		4.0		0.6		μs
Data setup time (reception)	t <sub>SU:DAT</sub>		250		100		ns
Data hold time (transmission) <sup>Note 2</sup>	t <sub>HD:DAT</sub>		0	3.45	0	0.9	μs
Setup time of stop condition	t <sub>SU:STO</sub>		4.0		0.6		μs
Bus-free time	t <sub>BUF</sub>		4.7		1.3		μs

**Notes** 1. The first clock pulse is generated after this period when the start/restart condition is detected.

2. The maximum value (MAX.) of  $t_{HD:DAT}$  is during normal transfer and a wait state is inserted in the ACK (acknowledge) timing.

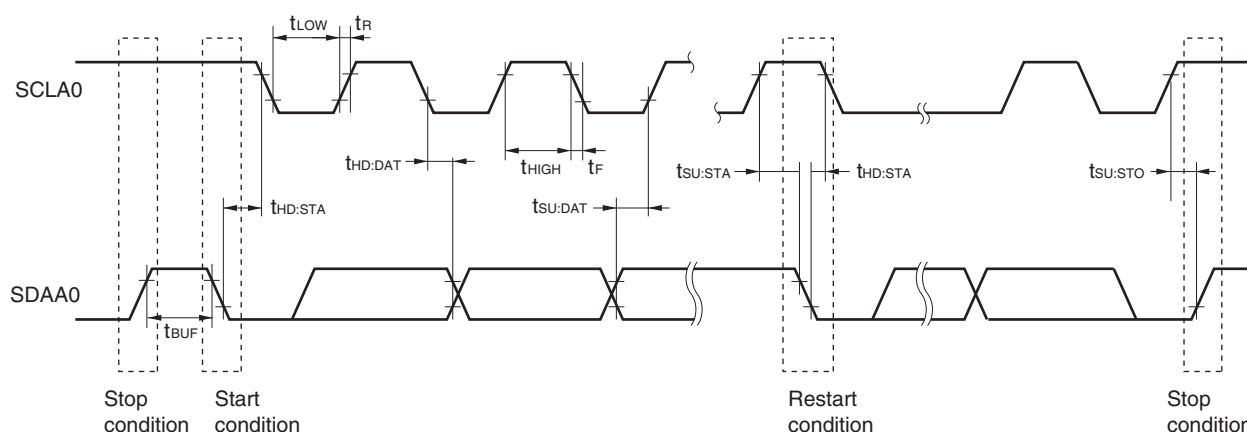
**Caution** Only in the 30-pin products, the values in the above table are applied even when bit 2 (PIOR2) in the peripheral I/O redirection register (PIOR) is 1. At this time, the pin characteristics ( $I_{OH1}$ ,  $I_{OL1}$ ,  $V_{OH1}$ ,  $V_{OL1}$ ) must satisfy the values in the redirect destination.

**Remark** The maximum value of  $C_b$  (communication line capacitance) and the value of  $R_b$  (communication line pull-up resistor) at that time in each mode are as follows.

Normal mode:  $C_b = 400\text{ pF}$ ,  $R_b = 2.7\text{ k}\Omega$

Fast mode:  $C_b = 320\text{ pF}$ ,  $R_b = 1.1\text{ k}\Omega$

IICA serial transfer timing



(4) When reference voltage (+) = Internal reference voltage (ADREFP1 = 1, ADREFP0 = 0), reference voltage (-) = AV<sub>REFM</sub> (ADREFM = 1), target pin: ANI0, ANI2, ANI3, and ANI16 to ANI22

(T<sub>A</sub> = -40 to +85°C, 2.4 V ≤ V<sub>DD</sub> ≤ 5.5 V, V<sub>SS</sub> = 0 V, Reference voltage (+) = V<sub>BGR</sub><sup>Note 3</sup>, Reference voltage (-) = AV<sub>REFM</sub>  
<sup>Note 4</sup> = 0 V, HS (high-speed main) mode)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RES		8			bit
Conversion time	t <sub>CONV</sub>	8-bit resolution	17		39	μs
Zero-scale error <sup>Notes 1, 2</sup>	EZS	8-bit resolution			±0.60	%FSR
Integral linearity error <sup>Note 1</sup>	ILE	8-bit resolution			±2.0	LSB
Differential linearity error <sup>Note 1</sup>	DLE	8-bit resolution			±1.0	LSB
Analog input voltage	V <sub>AIN</sub>		0		V <sub>BGR</sub> <sup>Note 3</sup>	V

**Notes** 1. Excludes quantization error (±1/2 LSB).

2. This value is indicated as a ratio (%FSR) to the full-scale value.

3. Refer to **28.6.2 Temperature sensor/internal reference voltage characteristics**.

4. When reference voltage (-) = V<sub>SS</sub>, the MAX. values are as follows.

Zero-scale error: Add ±0.35%FSR to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

Integral linearity error: Add ±0.5 LSB to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

Differential linearity error: Add ±0.2 LSB to the MAX. value when reference voltage (-) = AV<sub>REFM</sub>.

## 2.6.2 Temperature sensor/internal reference voltage characteristics

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ , HS (high-speed main) mode)**

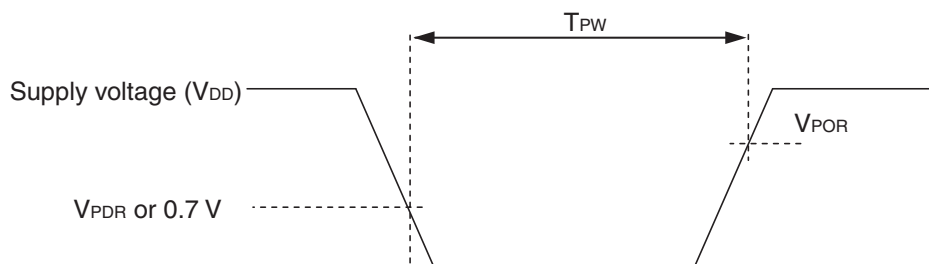
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Temperature sensor output voltage	$V_{TMPS25}$	Setting ADS register = 80H, $T_A = +25^\circ\text{C}$		1.05		V
Internal reference voltage	$V_{BGR}$	Setting ADS register = 81H	1.38	1.45	1.50	V
Temperature coefficient	$F_{VTMPS}$	Temperature sensor output voltage that depends on the temperature		-3.6		mV/ $^\circ\text{C}$
Operation stabilization wait time	$t_{AMP}$		5			$\mu\text{s}$

## 2.6.3 POR circuit characteristics

**( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection voltage	$V_{POR}$	Power supply rise time	1.47	1.51	1.55	V
	$V_{PDR}$	Power supply fall time	1.46	1.50	1.54	V
Minimum pulse width <sup>Note</sup>	$T_{PW}$		300			$\mu\text{s}$

**Note** Minimum time required for a POR reset when  $V_{DD}$  exceeds below  $V_{PDR}$ . This is also the minimum time required for a POR reset from when  $V_{DD}$  exceeds below 0.7 V to when  $V_{DD}$  exceeds  $V_{POR}$  while STOP mode is entered or the main system clock is stopped through setting bit 0 (HIOSTOP) and bit 7 (MSTOP) in the clock operation status control register (CSC).



**LVD detection voltage of interrupt & reset mode****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{PDR} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Interrupt and reset mode	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 0, 1, falling reset voltage		1.80	1.84	1.87	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	1.94	1.98	2.02	V
			Falling interrupt voltage	1.90	1.94	1.98	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.05	2.09	2.13	V
			Falling interrupt voltage	2.00	2.04	2.08	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.07	3.13	3.19	V
			Falling interrupt voltage	3.00	3.06	3.12	V
	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 0, falling reset voltage		2.40	2.45	2.50	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	2.56	2.61	2.66	V
			Falling interrupt voltage	2.50	2.55	2.60	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.66	2.71	2.76	V
			Falling interrupt voltage	2.60	2.65	2.70	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.68	3.75	3.82	V
			Falling interrupt voltage	3.60	3.67	3.74	V
	V <sub>LVD0</sub>	V <sub>POC2</sub> , V <sub>POC1</sub> , V <sub>POC0</sub> = 0, 1, 1, falling reset voltage		2.70	2.75	2.81	V
	V <sub>LVD1</sub>	LVIS1, LVIS0 = 1, 0	Rising reset release voltage	2.86	2.92	2.97	V
			Falling interrupt voltage	2.80	2.86	2.91	V
	V <sub>LVD2</sub>	LVIS1, LVIS0 = 0, 1	Rising reset release voltage	2.96	3.02	3.08	V
			Falling interrupt voltage	2.90	2.96	3.02	V
	V <sub>LVD3</sub>	LVIS1, LVIS0 = 0, 0	Rising reset release voltage	3.98	4.06	4.14	V
			Falling interrupt voltage	3.90	3.98	4.06	V

**2.6.5 Power supply voltage rising slope characteristics****( $T_A = -40$  to  $+85^\circ\text{C}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Power supply voltage rising slope	S <sub>VDD</sub>				54	V/ms

**Caution** Make sure to keep the internal reset state by the LVD circuit or an external reset until V<sub>DD</sub> reaches the operating voltage range shown in 28.4 AC Characteristics.

### 3.2 Oscillator Characteristics

#### 3.2.1 X1 oscillator characteristics

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Parameter	Resonator	Conditions	MIN.	TYP.	MAX.	Unit
X1 clock oscillation frequency ( $f_x$ ) <sup>Note</sup>	Ceramic resonator / crystal oscillator	$2.7\text{ V} \leq V_{DD} \leq 5.5\text{ V}$	1.0		20.0	MHz
		$2.4\text{ V} \leq V_{DD} < 2.7\text{ V}$	1.0		8.0	

**Note** Indicates only permissible oscillator frequency ranges. Refer to AC Characteristics for instruction execution time. Request evaluation by the manufacturer of the oscillator circuit mounted on a board to check the oscillator characteristics.

**Caution** Since the CPU is started by the high-speed on-chip oscillator clock after a reset release, check the X1 clock oscillation stabilization time using the oscillation stabilization time counter status register (OSTC) by the user. Determine the oscillation stabilization time of the OSTC register and the oscillation stabilization time select register (OSTS) after sufficiently evaluating the oscillation stabilization time with the resonator to be used.

**Remark** When using the X1 oscillator, refer to **5.4 System Clock Oscillator**.

#### 3.2.2 On-chip oscillator characteristics

( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )

Oscillators	Parameters	Conditions		MIN.	TYP.	MAX.	Unit
High-speed on-chip oscillator clock frequency <sup>Notes 1, 2</sup>	$f_{IH}$			1		24	MHz
High-speed on-chip oscillator clock frequency accuracy		R5F102 products	$T_A = -20$ to $+85^\circ\text{C}$	-1.0		+1.0	%
			$T_A = -40$ to $-20^\circ\text{C}$	-1.5		+1.5	%
			$T_A = +85$ to $+105^\circ\text{C}$	-2.0		+2.0	%
Low-speed on-chip oscillator clock frequency	$f_{IL}$				15		kHz
Low-speed on-chip oscillator clock frequency accuracy				-15		+15	%

**Notes** 1. High-speed on-chip oscillator frequency is selected by bits 0 to 3 of option byte (000C2H) and bits 0 to 2 of HOCODIV register.

2. This only indicates the oscillator characteristics. Refer to AC Characteristics for instruction execution time.

**(3) Peripheral functions (Common to all products)****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $2.4\text{ V} \leq V_{DD} \leq 5.5\text{ V}$ ,  $V_{SS} = 0\text{ V}$ )**

Parameter	Symbol	Conditions		MIN.	TYP.	MAX.	Unit
Low-speed onchip oscillator operating current	$I_{FIL}$ <sup>Note 1</sup>				0.20		$\mu\text{A}$
12-bit interval timer operating current	$I_{TMKA}$ <sup>Notes 1, 2, 3</sup>				0.02		$\mu\text{A}$
Watchdog timer operating current	$I_{WDT}$ <sup>Notes 1, 2, 4</sup>	$f_{IL} = 15\text{ kHz}$			0.22		$\mu\text{A}$
A/D converter operating current	$I_{ADC}$ <sup>Notes 1, 5</sup>	When conversion at maximum speed	Normal mode, $AV_{REFP} = V_{DD} = 5.0\text{ V}$		1.30	1.70	$\text{mA}$
			Low voltage mode, $AV_{REFP} = V_{DD} = 3.0\text{ V}$		0.50	0.70	$\text{mA}$
A/D converter reference voltage operating current	$I_{ADREF}$ <sup>Note 1</sup>				75.0		$\mu\text{A}$
Temperature sensor operating current	$I_{TMPS}$ <sup>Note 1</sup>				75.0		$\mu\text{A}$
LVD operating current	$I_{LVD}$ <sup>Notes 1, 6</sup>				0.08		$\mu\text{A}$
Self-programming operating current	$I_{FSP}$ <sup>Notes 1, 8</sup>				2.00	12.20	$\text{mA}$
BGO operating current	$I_{BGO}$ <sup>Notes 1, 7</sup>				2.00	12.20	$\text{mA}$
SNOOZE operating current	$I_{SNOZ}$ <sup>Note 1</sup>	ADC operation	The mode is performed <sup>Note 9</sup>		0.50	1.10	$\text{mA}$
			The A/D conversion operations are performed, Low voltage mode, $AV_{REFP} = V_{DD} = 3.0\text{ V}$		1.20	2.04	$\text{mA}$
		CSI/UART operation			0.70	1.54	$\text{mA}$

**Notes** 1. Current flowing to the  $V_{DD}$ .

2. When high speed on-chip oscillator and high-speed system clock are stopped.

3. Current flowing only to the 12-bit interval timer (excluding the operating current of the low-speed on-chip oscillator). The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$ , and  $I_{FIL}$  and  $I_{TMKA}$  when the 12-bit interval timer operates.4. Current flowing only to the watchdog timer (including the operating current of the low-speed on-chip oscillator). The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{WDT}$  when the watchdog timer operates.5. Current flowing only to the A/D converter. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$  or  $I_{DD2}$  and  $I_{ADC}$  when the A/D converter operates in an operation mode or the HALT mode.6. Current flowing only to the LVD circuit. The current value of the RL78 microcontrollers is the sum of  $I_{DD1}$ ,  $I_{DD2}$  or  $I_{DD3}$  and  $I_{LVD}$  when the LVD circuit operates.

7. Current flowing only during data flash rewrite.

8. Current flowing only during self programming.

9. For shift time to the SNOOZE mode, see **17.3.3 SNOOZE mode**.**Remarks** 1.  $f_{IL}$ : Low-speed on-chip oscillator clock frequency2. Temperature condition of the TYP. value is  $T_A = 25^\circ\text{C}$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.2}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

4. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 3** above to calculate the maximum transfer rate under conditions of the customer.
5. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.7 V ≤ V<sub>DD</sub> < 4.0 V and 2.3 V ≤ V<sub>b</sub> ≤ 2.7 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\} \times 3} \quad [\text{bps}]$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{2.0}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

6. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 5** above to calculate the maximum transfer rate under conditions of the customer.
7. The smaller maximum transfer rate derived by using f<sub>MCK</sub>/12 or the following expression is the valid maximum transfer rate.

Expression for calculating the transfer rate when 2.4 V ≤ V<sub>DD</sub> < 3.3 V, 1.6 V ≤ V<sub>b</sub> ≤ 2.0 V

$$\text{Maximum transfer rate} = \frac{1}{\{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\} \times 3} \quad [\text{bps}]$$

$$\text{Baud rate error (theoretical value)} = \frac{\frac{1}{\text{Transfer rate} \times 2} - \{-C_b \times R_b \times \ln(1 - \frac{1.5}{V_b})\}}{(\frac{1}{\text{Transfer rate}}) \times \text{Number of transferred bits}} \times 100 [\%]$$

\* This value is the theoretical value of the relative difference between the transmission and reception sides.

8. This value as an example is calculated when the conditions described in the “Conditions” column are met. Refer to **Note 7** above to calculate the maximum transfer rate under conditions of the customer.

**Caution** Select the TTL input buffer for the RxDq pin and the N-ch open drain output (V<sub>DD</sub> tolerance) mode for the TxDq pin by using port input mode register g (PIMg) and port output mode register g (POMg). **For V<sub>IH</sub> and V<sub>IL</sub>, see the DC characteristics with TTL input buffer selected.**

## 3.6.4 LVD circuit characteristics

**LVD Detection Voltage of Reset Mode and Interrupt Mode****( $T_A = -40$  to  $+105^\circ\text{C}$ ,  $V_{PDR} \leq V_{DD} \leq 5.5$  V,  $V_{SS} = 0$  V)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Detection supply voltage	$V_{LVD0}$	Power supply rise time	3.90	4.06	4.22	V
		Power supply fall time	3.83	3.98	4.13	V
	$V_{LVD1}$	Power supply rise time	3.60	3.75	3.90	V
		Power supply fall time	3.53	3.67	3.81	V
	$V_{LVD2}$	Power supply rise time	3.01	3.13	3.25	V
		Power supply fall time	2.94	3.06	3.18	V
	$V_{LVD3}$	Power supply rise time	2.90	3.02	3.14	V
		Power supply fall time	2.85	2.96	3.07	V
	$V_{LVD4}$	Power supply rise time	2.81	2.92	3.03	V
		Power supply fall time	2.75	2.86	2.97	V
	$V_{LVD5}$	Power supply rise time	2.70	2.81	2.92	V
		Power supply fall time	2.64	2.75	2.86	V
	$V_{LVD6}$	Power supply rise time	2.61	2.71	2.81	V
		Power supply fall time	2.55	2.65	2.75	V
	$V_{LVD7}$	Power supply rise time	2.51	2.61	2.71	V
		Power supply fall time	2.45	2.55	2.65	V
Minimum pulse width	$t_{LW}$		300			$\mu\text{s}$
Detection delay time					300	$\mu\text{s}$

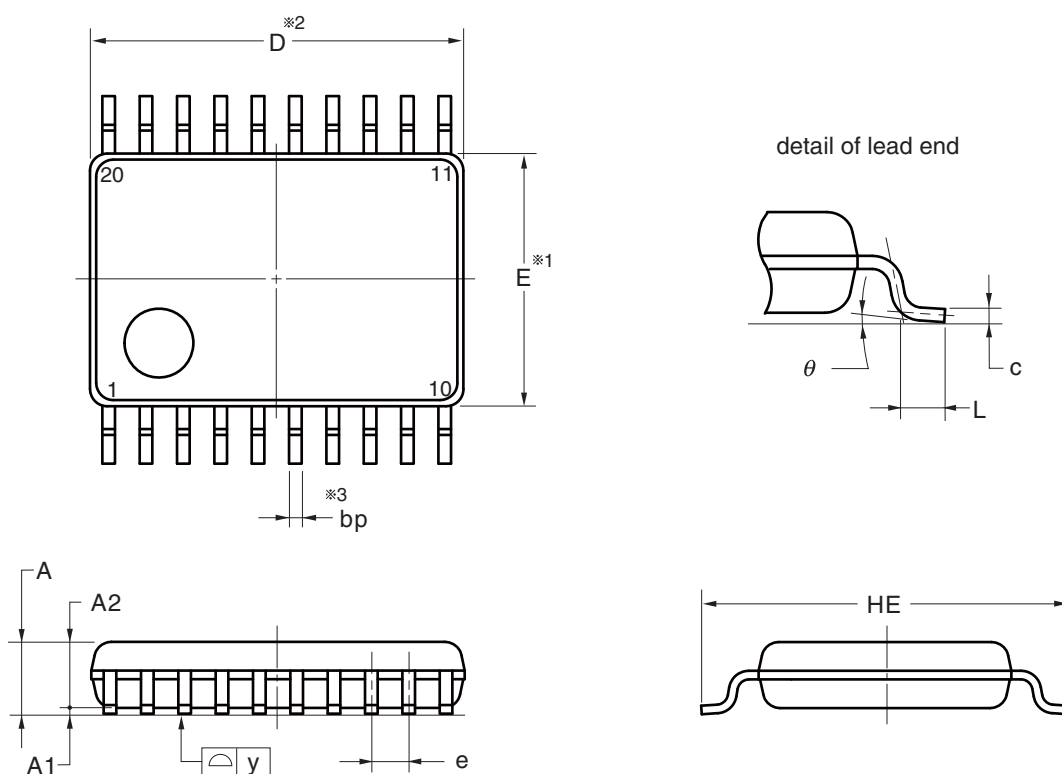
## 4. PACKAGE DRAWINGS

### 4.1 20-pin products

R5F1026AASP, R5F10269ASP, R5F10268ASP, R5F10267ASP, R5F10266ASP  
 R5F1036AASP, R5F10369ASP, R5F10368ASP, R5F10367ASP, R5F10366ASP  
 R5F1026ADSP, R5F10269DSP, R5F10268DSP, R5F10267DSP, R5F10266DSP  
 R5F1036ADSP, R5F10369DSP, R5F10368DSP, R5F10367DSP, R5F10366DSP  
 R5F1026AGSP, R5F10269GSP, R5F10268GSP, R5F10267GSP, R5F10266GSP

<R>

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-LSSOP20-4.4x6.5-0.65	PLSP0020JB-A	P20MA-65-NAA-1	0.1



#### NOTE

1. Dimensions "※1" and "※2" do not include mold flash.
2. Dimension "※3" does not include trim offset.

(UNIT:mm)

ITEM	DIMENSIONS
D	6.50±0.10
E	4.40±0.10
HE	6.40±0.20
A	1.45 MAX.
A1	0.10±0.10
A2	1.15
e	0.65±0.12
bp	0.22 <sup>+0.10</sup> <sub>-0.05</sub>
c	0.15 <sup>+0.05</sup> <sub>-0.02</sub>
L	0.50±0.20
y	0.10
θ	0° to 10°

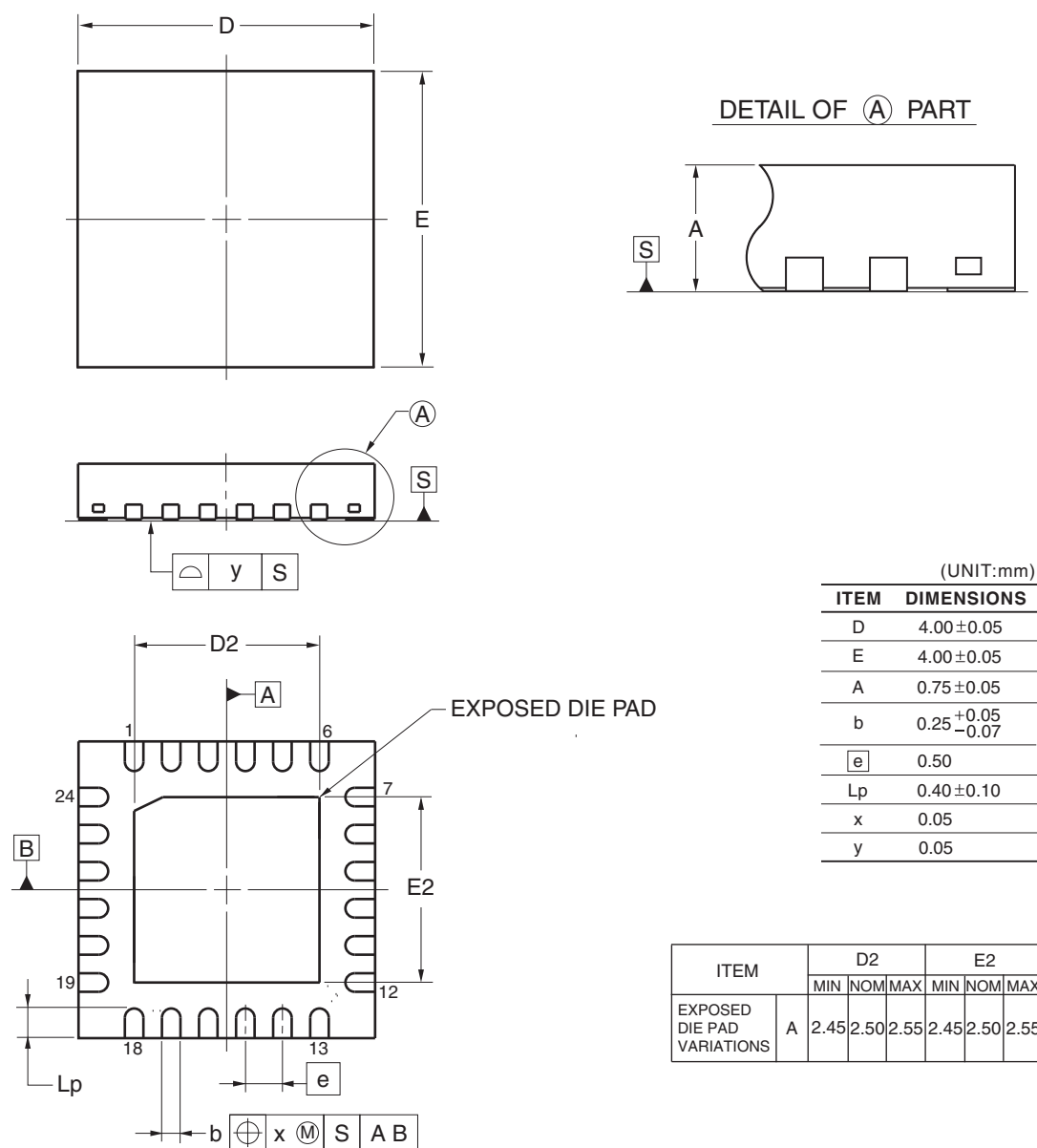
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## 4.2 24-pin products

R5F1027AANA, R5F10279ANA, R5F10278ANA, R5F10277ANA  
 R5F1037AANA, R5F10379ANA, R5F10378ANA, R5F10377ANA  
 R5F1027ADNA, R5F10279DNA, R5F10278DNA, R5F10277DNA  
 R5F1037ADNA, R5F10379DNA, R5F10378DNA, R5F10377DNA  
 R5F1027AGNA, R5F10279GNA, R5F10278GNA, R5F10277GNA

&lt;R&gt;

JEITA Package Code	RENESAS Code	Previous Code	MASS (TYP.) [g]
P-HWQFN24-4x4-0.50	PWQN0024KE-A	P24K8-50-CAB-1	0.04



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<b>Revision History</b>	<b>RL78/G12 Data Sheet</b>
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Rev.	Date	Description	
		Page	Summary
1.00	Dec 10, 2012	-	First Edition issued
2.00	Sep 06, 2013	1	Modification of 1.1 Features
		3	Modification of 1.2 List of Part Numbers
		4	Modification of Table 1-1. List of Ordering Part Numbers, Note, and Caution
		7 to 9	Modification of package name in 1.4.1 to 1.4.3
		14	Modification of tables in 1.7 Outline of Functions
		17	Modification of description of table in 2.1 Absolute Maximum Ratings (TA = 25°C)
		18	Modification of table, Note, and Caution in 2.2.1 X1 oscillator characteristics
		18	Modification of table in 2.2.2 On-chip oscillator characteristics
		19	Modification of Note 3 in 2.3.1 Pin characteristics (1/4)
		20	Modification of Note 3 in 2.3.1 Pin characteristics (2/4)
		23	Modification of Notes 1 and 2 in (1) 20-, 24-pin products (1/2)
		24	Modification of Notes 1 and 3 in (1) 20-, 24-pin products (2/2)
		25	Modification of Notes 1 and 2 in (2) 30-pin products (1/2)
		26	Modification of Notes 1 and 3 in (2) 30-pin products (2/2)
		27	Modification of (3) Peripheral functions (Common to all products)
		28	Modification of table in 2.4 AC Characteristics
		29	Addition of Minimum Instruction Execution Time during Main System Clock Operation
		30	Modification of figures of AC Timing Test Point and External Main System Clock Timing
		31	Modification of figure of AC Timing Test Point
		31	Modification of description and Note 2 in (1) During communication at same potential (UART mode)
		32	Modification of description in (2) During communication at same potential (CSI mode)
		33	Modification of description in (3) During communication at same potential (CSI mode)
		34	Modification of description in (4) During communication at same potential (CSI mode)
		36	Modification of table and Note 2 in (5) During communication at same potential (simplified I <sup>2</sup> C mode)
		38, 39	Modification of table and Notes 1 to 9 in (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)
		40	Modification of Remarks 1 to 3 in (6) Communication at different potential (1.8 V, 2.5 V, 3 V) (UART mode)
		41	Modification of table in (7) Communication at different potential (2.5 V, 3 V) (CSI mode)
		42	Modification of Caution in (7) Communication at different potential (2.5 V, 3 V) (CSI mode)
		43	Modification of table in (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (1/3)
		44	Modification of table and Notes 1 and 2 in (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (2/3)
		45	Modification of table, Note 1, and Caution 1 in (8) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode) (3/3)
		47	Modification of table in (9) Communication at different potential (1.8 V, 2.5 V, 3 V) (CSI mode)
		50	Modification of table, Note 1, and Caution 1 in (10) Communication at different potential (1.8 V, 2.5 V, 3 V) (simplified I <sup>2</sup> C mode)
		52	Modification of Remark in 2.5.2 Serial interface IICA
		53	Addition of table to 2.6.1 A/D converter characteristics
		53	Modification of description in 2.6.1 (1)
		54	Modification of Notes 3 to 5 in 2.6.1 (1)
		54	Modification of description and Notes 2 to 4 in 2.6.1 (2)

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